As a below named inventor, I hereby declare that:

| inventor (if only one nat  | e address, and citizenship are<br>me is listed below) or an orig   | inal, first and joint inven  | tor (if plural names are listed  | below) of the subject   |
|--|--|--|--|---|
|  | and for which a patent is soug   | ht on the invention entitle  | ed: SEMICONDUCTOR DEV  | ICES AND MANUFACTURING  |
| METHOD OF THE  | SAME, the  | e specification of which   |  |   |
| was filed on   | as U.S. Application  | or PCT International Appl  | ication No and was an  | nended (if applicable) on   |
| amended by any amenda<br>in the United States of<br>country before my or o<br>invention was not in put<br>I understand that I have | ve reviewed and understand ment referred to above. I do not a control of the cont | not know and do not believention thereof, or pater<br>than one year prior to the<br>d States of America more<br>with toward the Patent and   | eve that the same was ever known ted or described in any prinched date of this application. The than one year prior to the date of Trademark Office, and I are | town or used by others ted publication in any I further state that the late of this application. Eknowledge the duty to |
| patent or inventor's cert<br>the United States of A  | riority benefits under Title 35 ifficate, or §365(a) of any PC merica, listed below and habject matter in common with fority is claimed:   | T international application ve also identified below   | on which designated at least<br>v any foreign application for  | one country other than or patent or inventor's  |
|  | upp. No.<br>00-377379 December   | er 12, 2000  | Priority Claimed Un<br>Yes X   | nder 35 USC §119<br>No  |
| PCT international appli<br>claim of the present app<br>by the first paragraph o<br>patentability as defined                        | fit under Title 35, United State cation designating the United lication is not disclosed in the Title 35, United States Codin Title 37, Code of Federal enational or PCT international   | States of America, listed prior United States or P to \$112, I acknowledge the Regulations \$1.56, while I filing date of this applications. | ed below and, insofar as the<br>CT international application in<br>the duty to disclose information<br>to became available between                             | subject matter of each in the manner provided on which is material to a the filing date of the                          |
|  |  |  |  |   |
| Delief are believed to be like so made are punish  | I statements made herein of ne true; and further that these sable by fine or imprisonment tents may jeopardize the valid   | tatement were made with or both, under Section   | n the knowledge that willful f<br>1001 of Title 18 of the United   | alse statements and the   |
| to be taken in the Patent  | J.S. attorneys named herein to<br>t and Trademark Office regard<br>the event of a change in the p<br>ndersigned.   | ling this application, with  | out direct communication be  | tween the U.S. attorney   |
|  | 7: The following attorneys are rk Office connected therewith   |  | osecute this application and t   | ransact all business in   |
| Customer Numbe   | er and Bar Code Label  |  | <b>2337</b> 0 -  |   |
|  |  | PATEN  | T TRADEMARK OFFICE   |   |
| Send correspondence to:  | John S. Pratt<br>KILPATRICK STOCKTON,<br>Suite 2800, 1100 Peachtree Stro<br>Atlanta, GA 30309-4530   |  | rirect telephone calls (404) 815-6 oger Frost  | 5500 to:  |
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|  | o Sanken Electric Co   | <i>o</i> A   | Kitano, Niiza-shi, S   |   |
| Inventor's signature   | Gideyaki Gnd   | Date: I  | November 28, 2001  |   |

Additional inventors are being named on separately numbered sheets attached hereto.